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IN THE CLAIMS:

This listing of claims will replace all prior versions, and listings, of claims in the application:

- 1. (Currently amended) A method far treating a surface of at least one a substrate, wherein the at least one substrate is placed in a process chamber, wherein and a plasma is generated by at least one a plasma source, the at least one plasma source being a cascade source [[(9)]], wherein at least one a cathode [[(4)]] of the cascade source [[(3)]] is present in a prechamber [[(6)]] in which, during use, a relatively high pressure [[(P2)]] prevails compared to a relatively low pressure [[(P1)]] prevailing in the process chamber [[(1)]], wherein, via a relatively narrow channel [[(7)]] bounded by mutually electrically insulated cascade plates [[(8)]], the prechamber [[(6)]] opens into the process chamber [[(1)]], such that, during use, the plasma extends via the relatively narrow channel [[(7)]] into the process chamber [[(1)]], characterized in that the method comprising, during the treatment, at least one moving the plasma source [[(3)]] and/or at least one optionally provided a treatment fluid supply source is moved relative to the substrate surface.
- 2. (Currently amended) A method according to claim 1, characterized in that wherein the plasma source [[(3)]] and/or the optional treatment fluid supply source is rotated about at least one a rotation axis (14, 15), which axis (14, 15) that extends substantially parallel to the substrate surface.
- 3. (Currently amended) A method according to claim 1 [[or 2]], characterized in that wherein the plasma source [[(3)]] and/or the optional treatment fluid supply source is moved in a direction towards the substrate surface or away from it.
- 4. (Currently amended) A method according to <u>claim 1</u> any one of the preceding claims, eharacterized in that <u>wherein</u> the plasma source [[(3)]] and/or the optional treatment fluid supply source is moved in at least one lateral direction relative to the substrate surface.
- 5. (Currently amended) A method according to <u>claim 1</u> any one of the preceding claims, eharacterized in that <u>wherein</u> the plasma source [[(3)]] and/or the <u>optional</u> treatment fluid

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supply source is rotated about an axis extending perpendicularly relative to the substrate surface.

- 6. (Currently amended) A method according to claim 1 any one of the preceding claims, characterized in that wherein a treatment fluid is added to the plasma, in particular for the purpose of PECVD.
- 7. (Currently amended) A method according to claim 6, characterized in that wherein the amount of treatment fluid to be added to the plasma is related to the movement of the at least one plasma source [[(3)]].
- 8. (Currently amended) A method according to claim 6 [[or 7]], eharacterized in that a wherein the treatment fluid is supplied into the [[a]] prechamber [[(6)]] of the cascade source [[(3)]], near [[a]] the cascade source cathode [[(4)]] present in [[this]] the prechamber [[(6)]].
- 9. (Currently amended) A method according to at least claim 6 [[or 7]], characterized in that wherein, between the at least one plasma source [[(3)]] and the substrate surface, at least one the treatment fluid supply source [[(9)]] is arranged to add the treatment fluid to the plasma.
- 10. (Currently amended) A method according to claim 9 characterized in that wherein, during the treatment, the at least one treatment fluid supply source [[(9)]] is moved relative to the substrate surface, wherein and the movement of the treatment fluid supply source [[(9)]] is related to the movement of the at least one plasma source [(3)].
- 11. (Currently amended) A method according to claim 1 any one of the preceding claims, characterized in that wherein the at least one plasma source [[(3)]] is moved such that each part of the substrate surface undergoes substantially the same extent of treatment, in particular in that each part of [[this]] the substrate surface is reached by the same amount of plasma.

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- 12. (Currently amended) A method according to <u>claim 1</u> any one of claims 1-10, eharacterized in that <u>wherein</u> the <u>at least one</u> plasma source [[(3)]] is moved such that at least a first part of the substrate surface undergoes substantially a greater extent of treatment than a second part of [[this]] <u>the substrate</u> surface, <u>in particular</u> in that the first surface part is reached by a larger amount of plasma than the second surface part.
- 13. (Currently amended) A method according to <u>claim 1</u> any one of the preceding claims, wherein said plasma source [[(3)]] is mounted on the process chamber.
- 14. (Currently amended) A method according to <u>claim 1</u> any one of claims 1-12, wherein said substrate is provided with at least one cavity at least partly bounded by said substrate surface, wherein, during treatment, at least a part of said plasma source and/or at least said treatment fluid supply source is and/or has been introduced into said substrate cavity.
- 15. (Currently amended) A method according to <u>claim 1</u> any one of the preceding claims, wherein, during the treatment, said plasma source [[(3)]] and/or treatment fluid supply source carries out at least one three-dimensional movement.
- 16. (Currently amended) An apparatus for treating a surface of at least one <u>a</u> substrate, wherein the apparatus is provided with comprising: a process chamber and at least one <u>a</u> plasma source, the <u>at least one</u> plasma source being a cascade source [[(3)]], wherein <u>at least one a</u> cathode [[(4)]] of the cascade source [[(3)]] is present in a prechamber [[(6)]] in which, during use, a relatively high pressure [[(P2)]] prevails compared to a relatively low pressure, [[(P1)]] prevailing in the process chamber [[(1)]], wherein, via a relatively narrow channel [[(7)]] bounded by mutually electrically insulated cascade plates [[(8)]], the prechamber [[(6)]] opens into the process chamber [[(1)]], such that, during use, the plasma extends via the relatively narrow channel [[(7)]] into the process chamber [[(1)]], eharacterized in that the at least one and the plasma source [[(3)]] and/or at least one optionally provided <u>a</u> treatment fluid supply source is movably arranged.
- 17. (Currently amended) An apparatus according to claim 16, eharacterized in that the apparatus is provided with wherein a resilient means (11) element is arranged to exert [[such]] a spring force on the at least one plasma source [[(3)]] such that, under the influence

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of [[this]] the spring force, the plasma source [[(3)]] can move to a starting position when the plasma source [[(3)]] is not in [[this]] the starting position.

- 18. (Currently amended) An apparatus according to <u>claim 16</u> any one of claims 16-17, eharacterized in that <u>wherein</u>, between the at least one plasma source [[(3)]] and the process chamber [[(1)]], a flexible, substantially gastight sealing is provided.
- 19. (Currently amended) An apparatus according to <u>claim 1</u> any one of claims 16-18, eharacterized in that <u>wherein</u> the apparatus is provided with a first housing part [[(16)]] and a second housing part [[(17)]], wherein the <u>at least one</u> plasma source is provided on the first housing part [[(16)]], wherein <u>and</u> the first housing part [[(16)]] is coupled to the second housing part [[(17)]] in a substantially gastight and movable manner, in particular by a thinwalled stainless-steel bellows (11).
- 20. (Currently amended) An apparatus according to <u>claim 16</u> any one of claims 16-19, <u>characterized in that wherein</u> the apparatus is provided with at <u>least one a motor (12, 13) for the purpose of moving configured to move</u> the <u>at least one plasma source [[(3)]].</u>
- 21. (Currently amended) An apparatus according to <u>claim 16 any one of claims 16-20</u>, eharacterized in that <u>wherein</u> the <u>at least one</u> plasma source [[(3)]] is arranged so as to be rotatable about <u>a at least one</u> first [[(14)]] rotation axis and [[one]] <u>a second rotation axis [[(15)]]</u>, wherein the first and second rotation <u>axes axis (14 and 15 respectively)</u> each extend substantially parallel to the substrate surface and in a different direction.
- 22. (Currently amended) An apparatus according to <u>claim 16</u> one of claims 16-21, eharacterized in that <u>wherein</u> the process chamber [[(1)]] is provided with at least one <u>the</u> treatment fluid supply source [[(9)]] to add a treatment fluid to the plasma, in particular for the purpose of PECVD.
- 23. (Currently amended) An apparatus according to claim 22, characterized in that the at least one wherein treatment fluid supply source [[(9)]] is arranged to add treatment fluid to the plasma extending via each relatively narrow caseade source the channel [[(7)]] into the process chamber [[(1)]].

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24. (Currently amended) An apparatus according to claim 22 or 23, characterized in that wherein the at least one treatment fluid supply source [[(9)]] is provided with at least one a plasma passage through which the plasma extends during use.

- 25. (Currently amended) An apparatus according to <u>claim 22</u> any one of claims 22-24, eharacterized in that <u>wherein</u> the at least one treatment fluid supply source [[(9)]] is movably arranged in the process chamber [[(1)]].
- 26. (Currently amended) An apparatus according to claim 25, eharacterized in that wherein the at least one treatment fluid supply source [[(9)]] is coupled to the at least one plasma source, such that the movement of the at least one treatment fluid supply source [[(9)]] is related to the movement of the at least one plasma source [[(3)]].
- 27. (Currently amended) An apparatus according to <u>claim 16</u> any one of claims 16-26, wherein said plasma source is mounted on the process chamber.
- 28. (Currently amended) An apparatus according to <u>claim 16</u> any one of claims 16-27, wherein said plasma source and/or at least said treatment fluid supply source are arranged to carry out one or more three-dimensional movements.
- 29. (Currently amended) An apparatus according to <u>claim 16</u> any one of claims 16-28, wherein the apparatus is at least arranged to carry out PECVD.
- 30. (Currently amended) A substrate provided with a surface with at least one layer of material deposited on it, characterized in that wherein the layer has been deposited using a method according to any one of claims 1-15 and/or using an apparatus according to any one of claims 1-29 claim 1.
- 31. (New) A method according to claim 6, wherein the treatment fluid is added to the plasma for the purpose of PECVD.

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32. (New) An apparatus according to claim 19, wherein first housing part is coupled to the second housing part by a thin-walled stainless-steel bellows.